NSN 5961-01-170-0111

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-170-0111 **Inclosure Material:** Ceramic and glass **Overall Length:** 0.785 inches **Terminal Length:** 0.188 inches **Overall Height:** 0.160 inches **Overall Width:** 0.310 inches **Component Name And Quantity:** 5 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 5.0 emitter to base voltage, static, collector open all transistor and 15.0 collector to emitter voltage/static/base open all transistor and 20.0 collector to base voltage/static/emitter open all transistor **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No